19-3569; Rev 2; 4/07

powered systems.

ble range.



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## Interleaved High-Efficiency, Dual Power-Supply Controllers for Notebook Computers

### **General Description**

The MAX8716/MAX8717/MAX8756/MAX8757 are dual.

step-down, interleaved, fixed-frequency, switch-mode power-supply (SMPS) controllers with synchronous rec-

tification. The MAX8716/MAX8717/MAX8756/MAX8757

are intended for main (5V/3.3V) power generation, while

the MAX8756 is optimized for I/O power rails in battery-

Fixed-frequency operation with optimal interleaving min-

imizes input ripple current from the lowest input voltages

up to the 26V maximum input. Optimal 40/60 interleav-

ing allows the input voltage to go down to 8.3V before

duty-cycle overlap occurs in 5V/3.3V applications, com-

pared to 180° out-of-phase regulators where the dutycycle overlap occurs when the input drops below 10V.

Accurate output current limit is achieved using a sense resistor. Alternatively, power dissipation can be

reduced using lossless inductor current sensing.

Independent ON/OFF controls and power-good signals

allow flexible power sequencing. Soft-start reduces inrush current, while soft-stop gradually ramps the out-

The MAX8716 is available in a 24-pin thin QFN package, and the MAX8717/MAX8756/MAX8757 are avail-

Applications

put voltage down preventing negative voltage dips. A low-noise mode maintains high light-load efficiency while keeping the switching frequency out of the audi**Features** 

- Fixed Switching Frequency 200kHz, 300kHz, or 500kHz 250kHz, 300kHz, or 400kHz (MAX8756 Only)
- No Current-Sense Resistor Required
- 40/60 Optimal Interleaving
- Reduced Input-Capacitor Requirement
- ◆ Output Voltage Fixed or Adjustable Outputs (Dual Mode<sup>™</sup>) 3.3V/5V Fixed or 1V to 5.5V Adjustable 1.5V/1.8V Fixed or 1V to 2.3V Adjustable (MAX8756 Only)
- ♦ 4V to 26V Input Range
- Independently Selectable PWM, Skip, and Low-Noise Mode Operation
- Soft-Start and Soft-Stop
- ♦ 2V Precision Reference with 0.75% Accuracy
- Independent Power-Good Outputs

### Ordering Information

PART	TEMP RANGE	PIN- PACKAGE	PKG CODE
MAX8716ETG	-40°C to +85°C	24 Thin QFN 4mm x 4mm	T2444-4
MAX8716ETG+	-40°C to +85°C	24 Thin QFN 4mm x 4mm	T2444-4
MAX8717ETI	-40°C to +85°C	28 Thin QFN 5mm x 5mm	T2855-6

+Denotes a lead-free package.

Ordering Information continued at end of data sheet.

### Main or I/O Power Supplies

PDAs and Mobile Communicators

able in a 28-pin thin QFN package.

Dual Mode is a trademark of Maxim Integrated Products, Inc.

2 to 4 Li+ Cell Battery-Powered Devices Notebook and Subnotebook Computers

### Pin Configurations



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\_ Maxim Integrated Products 1

For pricing, delivery, and ordering information, please contact Maxim/Dallas Direct! at 1-888-629-4642, or visit Maxim's website at www.maxim-ic.com.

### ABSOLUTE MAXIMUM RATINGS (Note 1)

V<sub>DD</sub>, V<sub>CC</sub>, CSL1, CSH1, CSL2, CSH2 to AGND .....-0.3V to +6V ON1, ON2, SKIP1, SKIP2, PGOOD1,

PGOOD2 to AGND	0.3V to +6V
FB1, FB2, ILIM1, ILIM2, FSEL to AGND	
REF to AGND	0.3V to (V <sub>CC</sub> + $0.3V$ )
BST1, BST2 to AGND	0.3V to +36V
LX1 to BST1	6V to +0.3V
LX2 to BST2	6V to +0.3V
DH1 to LX1	$\dots -0.3V$ to (V <sub>BST1</sub> + 0.3V)
DH2 to LX2	0.3V to (V <sub>BST2</sub> + 0.3V)
DL1, DL2 to PGND	0.3V to $(V_{DD} + 0.3V)$
AGND to PGND	0.3V to +0.3V

REF Short Circuit to AGND REF Current	Continuous
Continuous Power Dissipation ( $T_A = +70^{\circ}C$ )	
24-Pin Thin QFN 4mm x 4mm (derate 20.8m)	W/°C
above +70°C)	1666.7mW
28-Pin Thin QFN 5mm x 5mm (derate 21.3m)	W/°C
above +70°C)	1702.1mW
Operating Temperature Range	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (soldering, 10s)	+300°C

Note 1: For the 24-pin TQFN version, AGND and PGND refer to a single pin designated GND.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1,  $V_{IN}$  = 12V, FSEL = REF,  $\overline{SKIP}$  = 0,  $V_{ON}$  =  $V_{ILIM}$  =  $V_{CC}$  =  $V_{DD}$  = 5V,  $T_A$  = 0°C to +85°C, unless otherwise noted. Typical values are at  $T_A$  = +25°C.)

PARAMETER	SYMBOL	CONDI	TIONS	MIN	ТҮР	MAX	UNITS	
INPUT SUPPLIES		·						
Innut Valtage Denge	VIN					26	V	
input voltage Range	VBIAS	V <sub>CC</sub> , V <sub>DD</sub>		4.5		5.5	v	
V <sub>CC</sub> Undervoltage-Lockout	Vunno	200mV typical	V <sub>CC</sub> rising	3.9	4.15	4.4	V	
Threshold	VUVLO	hysteresis	V <sub>CC</sub> falling	3.7	3.95	4.2	v	
Quiescent Supply Current (V <sub>CC</sub> )	Icc	CSL_ and FB_ forced above their regulation	MAX8716, MAX8717, MAX8757		0.8	1.3	mA	
		points	MAX8756		1	1.8		
Quiescent Supply Current (V <sub>DD</sub> )	IDD	CSL_ and FB_ forced above their regulation points			< 1	5	μA	
Shutdown Supply Current (V <sub>CC</sub> )		ON1 = ON2 = GND			< 1	5	μA	
Shutdown Supply Current (V <sub>DD</sub> )		ON1 = ON2 = GND			< 1	5	μA	
MAIN SMPS CONTROLLERS								
PWM1 Output Voltage in	Vout1	$\frac{V_{IN} = 6V \text{ to } 26V,}{SKIP1} = V_{CC},$	MAX8716, MAX8717, MAX8757	3.265	3.30	3.365	V	
Fixed Mode		zero to full load	MAX8756	1.484	1.50	1.530		
PWM2 Output Voltage in	V <sub>OUT2</sub>	$V_{IN} = 6V$ to 26V, SKIP2 = Vcc	MAX8716, MAX8717, MAX8757	4.94	5.00	5.09	V	
Fixed Mode		zero to full load	MAX8756	1.778	1.800	1.832		
Feedback Voltage in Adjustable		$V_{IN} = 6V$ to 26V, FB1 or duty factor = 20% to 80	r FB2, )%	0.990	1.005	1.020	V	
Mode (Note 2)	VFB_	$V_{IN} = 6V$ to 26V, FB1 or FB2, duty factor = 50%		0.995	1.005	1.015	V	
Output-Voltage-Adjust Bange		Either SMPS	MAX8716, MAX8717, MAX8757	1.0		5.5	V	
			MAX8756	1.0		2.3	•	

### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN} = 12V$ , FSEL = REF,  $\overline{SKIP} = 0$ ,  $V_{ON} = V_{ILIM} = V_{CC} = V_{DD} = 5V$ ,  $T_A = 0^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	COND	ITIONS	MIN	ТҮР	MAX	UNITS
FB1, FB2 Fixed-Mode Threshold Voltage		Dual Mode comparato	r	1.9		2.1	V
Feedback Input Leakage Current		FB1 = 1.1V, FB2 = 1.1	V	-0.1		+0.1	μA
DC Load Regulation		Either SMPS, $\overline{SKIP} = V$	V <sub>CC</sub> , zero to full load		-0.1		%
Line-Regulation Error		Either SMPS, 4V < V <sub>IN</sub>	< 26V		0.03		%/V
FB_ Input Bias Current	I <sub>FB</sub> _	V <sub>FB</sub> = 0 to 5.5V		-0.1		+0.1	μA
		FSEL = GND	MAX8716, MAX8717, MAX8757	170	200	230	
			MAX8756	215	250	285	Ţ
Operating Frequency	fosc	FSEL = REF (Note 3)		270	300	330	kHz
		$FSEL = V_{CC}$	MAX8716, MAX8717, MAX8757	425	500	575	
			MAX8756	340	400	460	
		FSEL = GND		97.5	99		
Maximum Duty Factor	DMAX	FSEL = REF (Note 3)		97.5	99		%
		FSEL = V <sub>CC</sub>		97.5	99		
Minimum On-Time	ton(min)	(Note 4)				200	ns
CMDC1 to CMDC2 Dhoose Chift		SMPS2 starts after SMPS1			40		%
SMPST to SMPSZ Phase Shilt					144		Degrees
Soft-Start Ramp Time	tSSTART	Measured from the rising edge of ON_ to full scale, REF = 2V			2		ms
Soft-Stop Ramp Time	tSSTOP	Measured from the fall scale	ing edge of ON_ to full		4		ms
CURRENT LIMIT							
ILIM_ Adjustment Range				0.5		VREF	V
Current-Limit Threshold (Fixed)	VLIMIT_	V <sub>CSH</sub> - V <sub>CSL</sub> , ILIM	= V <sub>CC</sub> (Note 3)	45	50	55	mV
Current-Limit Threshold			$V_{ILIM} = 2.00V$	190	200	210	
(Adjustable)	VLIMIT_	VCSH VCSL _	$V_{ILIM} = 1.00V$	94	100	106	mv
Current-Limit Threshold		V <sub>CSH</sub> - V <sub>CSL</sub> , <u>SKIP</u> (Note 3)	= ILIM_ = V <sub>CC</sub>	-67	-60	-53	mV
(Negative)	VNEG	$V_{CSH_} - V_{CSL_}$ , $\overline{SKIP_} = V_{CC}$ , adjustable mode, percent of current limit			-120		%
Current-Limit Threshold (Zero Crossing)	V <sub>ZX</sub>	$V_{CSH} - V_{CSL}$ , $\overline{SKIP}$ = GND or REF			3		mV
			ILIM_ = V <sub>CC</sub> (Note 3)	6	10	14	mV
Idle Mode™ Threshold	VIDLE	$\frac{V_{CSH}}{SKIP} = GND$	With respect to current-limit threshold		20		%

Idle Mode is a trademark of Maxim Integrated Products, Inc.



### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN} = 12V$ , FSEL = REF,  $\overline{SKIP} = 0$ ,  $V_{ON} = V_{ILIM} = V_{CC} = V_{DD} = 5V$ ,  $T_A = 0^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	COND	TIONS	MIN	ТҮР	MAX	UNITS
		$V_{CSH} - V_{CSL}$	MAX8716, MAX8717, MAX8757	2.5	5	7.5	mV
		$ILIM_ = V_{CC}$ (Note 3)	MAX8756	1	2.5	4	
Low-Noise-Mode Threshold	VIDLE	$\frac{V_{CSH_}}{SKIP_} = REF$ with	MAX8716, MAX8717, MAX8757		10		0/
		respect to current- limit threshold	MAX8756		5		%
ILIM_ Leakage Current						0.1	μA
Reference Load Regulation	$\Delta V_{REF}$	$I_{REF} = 0\mu A$ to $50\mu A$				10	mV
Reference Sink Current				10			μA
REF Lockout Voltage	VREF(UVLO)	Rising edge, hysteres	is = 50mV		1.8		V
FAULT DETECTION							
Output Overvoltage Trip Threshold		MAX8716/MAX8717/M	1AX8756 only	11	15	19	%
Output Overvoltage Fault-Propagation Delay	tovp	50mV overdrive, MAX8716/MAX8717/MAX8756 onlv			10		μs
Output Undervoltage-Protection Trip Threshold		With respect to error-comparator threshold		65	70	75	%
Output Undervoltage Fault-Propagation Delay	tuvp	50mV overdrive			10		μs
Output Undervoltage-Protection Blanking Time	<b>t</b> BLANK	From rising edge of ON_			6144		1/fosc
PGOOD_ Lower Trip Threshold		With respect to error-o hysteresis = 1%	comparator threshold,	-12.5	-10	-8.0	%
PGOOD_ Propagation Delay	tpgood_	Falling edge, 50mV ov	verdrive		10		μs
PGOOD_ Output Low Voltage		$I_{SINK} = 4mA$				0.4	V
PGOOD_ Leakage Current	IPGOOD_	High state, PGOOD_ f	orced to 5.5V			1	μA
Thermal-Shutdown Threshold	TSHDN	Hysteresis = 15°C			+160		°C
GATE DRIVERS							
DH_ Gate-Driver On-Resistance	R <sub>DH</sub>	BST LX_ forced to 5	SV (Note 5)		1.5	5	Ω
DL_ Gate-Driver On-Resistance	Dev	DL_, high state			1.7	5	0
(Note 5)	RDL	DL_, low state			0.6	3	52
DH_ Gate-Driver Source/Sink Current	IDH	DH_ forced to 2.5V, BST LX_ forced to 5V			2		A
DL_ Gate-Driver Source Current	I <sub>DL</sub> (SOURCE)	DL_ forced to 2.5V			1.7		А
DL_ Gate-Driver Sink Current	IDL (SINK)	DL_ forced to 2.5V			3.3		A
Doad Timo	torap	DL_ rising			35		200
	UEAD	DH_ rising			26		115
LX_, BST_ Leakage Current		$V_{BST_} = V_{LX_} = 26V$			< 2	20	μA

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### ELECTRICAL CHARACTERISTICS (continued)

(Circuit of Figure 1,  $V_{IN} = 12V$ , FSEL = REF,  $\overline{SKIP} = 0$ ,  $V_{ON} = V_{ILIM} = V_{CC} = V_{DD} = 5V$ ,  $T_A = 0^{\circ}C$  to +85°C, unless otherwise noted. Typical values are at  $T_A = +25^{\circ}C$ .)

PARAMETER	SYMBOL	CONDITIONS		ТҮР	МАХ	UNITS
INPUTS AND OUTPUTS						
Logic Input Current		ON1, ON2	-1		+1	μA
ON_ Input Voltage		Rising edge, hysteresis = 225mV	1.2	1.7	2.2	V
Tri-Level Input Logic		SKIP1, SKIP2, FSEL, high	V <sub>CC</sub> - 0.2			V
Input Leakage Current		SKIP1, SKIP2, FSEL, 0V, or V <sub>CC</sub>	-3		+3	μA
Input Leakage Current		ILIM1, ILIM2, 0V, or V <sub>CC</sub>	-0.1		+0.1	μA
Input Leakage Current		CSH_, 0V, or V <sub>DD</sub>	-0.1		+0.1	μA
Input Bias Current		CSL_, 0V, or V <sub>DD</sub>		25	50	μA

### **ELECTRICAL CHARACTERISTICS**

(Circuit of Figure 1,  $V_{IN}$  = 12V, FSEL = REF,  $\overline{SKIP}$  = 0,  $V_{ON}$  =  $V_{ILIM}$  =  $V_{CC}$  =  $V_{DD}$  = 5V,  $T_A$  = -40°C to +85°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	МАХ	UNITS
INPUT SUPPLIES		·					
Input Voltage Denge	V <sub>IN</sub>					26	
Input voltage Range	VBIAS	V <sub>CC</sub> , V <sub>DD</sub>		4.5		5.5	v
Quiescent Supply Current (V <sub>CC</sub> )	Icc	CSL_ and FB_ forced above their	MAX8716, MAX8717, MAX8757			1.3	mA
		regulation points	MAX8756			1.8	
Quiescent Supply Current (VDD)	IDD	CSL_ and FB_ forced points	CSL_ and FB_ forced above their regulation points			5	μA
Shutdown Supply Current (V <sub>CC</sub> )		ON1 = ON2 = GND				5	μA
Shutdown Supply Current (V <sub>DD</sub> )		ON1 = ON2 = GND	ON1 = ON2 = GND			5	μA
MAIN SMPS CONTROLLERS		·					
PWM1 Output Voltage in	Vout1	$V_{IN} = 6V$ to 26V, SKIP1 = V <sub>CC</sub> ,	MAX8716, MAX8717, MAX8757	3.255		3.375	V
Fixed Mode		zero to full load	MAX8756	1.480		1.534	
PWM2 Output Voltage in	Vout2	$V_{IN} = 6V$ to 26V, SKIP2 = V <sub>CC</sub> ,	MAX8716, MAX8717, MAX8757	4.925		5.105	V
Fixed Mode	0012	zero to full load	MAX8756	1.773		1.838	
Feedback Voltage in Adjustable Mode	V <sub>FB</sub> _	$V_{IN} = 6V$ to 26V, FB1 duty factor = 20% to 8	or FB2, 80% (Note 1)	0.987		1.023	V
Output Voltage Adjust Range		Either SMPS	MAX8716, MAX8717, MAX8757	1.0		5.5	V
			MAX8756	1.0		2.3	
FB1, FB2 Fixed-Mode Threshold Voltage		Dual Mode comparate	or	1.9		2.1	V



### **ELECTRICAL CHARACTERISTICS (continued)**

(Circuit of Figure 1,  $V_{IN}$  = 12V, FSEL = REF,  $\overline{SKIP}$  = 0,  $V_{ON}$  =  $V_{ILIM}$  =  $V_{CC}$  =  $V_{DD}$  = 5V,  $T_A$  = -40°C to +85°C, unless otherwise noted.) (Note 6)

PARAMETER	SYMBOL	CONE	DITIONS	MIN	ТҮР	MAX	UNITS
		FSEL = GND	MAX8716, MAX8717, MAX8757	170		230	
			MAX8756	215		285	
Operating Frequency	fosc	FSEL = REF (Note 3)		270		330	kHz
		FSEL = V <sub>CC</sub>	MAX8716, MAX8717, MAX8757	425		575	
			MAX8756	340		460	
		FSEL = GND		97.5			
Maximum Duty Factor	DMAX	FSEL = REF (Note 3)		97.5			%
		$FSEL = V_{CC}$		97.5			
Minimum On-Time	ton(MIN)	(Note 4)				200	ns
CURRENT LIMIT							
ILIM_ Adjustment Range				0.5		V <sub>REF</sub>	V
Current-Limit Threshold (Fixed)	V <sub>LIMIT</sub> _	V <sub>CSH</sub> V <sub>CSL</sub> _, ILIM_	= V <sub>CC</sub> (Note 3)	44		56	mV
Current-Limit Threshold	Market and the second s		$V_{ILIM} = 2.00V$	188		212	m)/
(Adjustable)	VLIMI1_	VCSH VCSL _	$V_{ILIM} = 1.00V$	93		107	ΠV
REFERENCE (REF)							
Reference Voltage	VREF	$V_{CC} = 4.5V$ to 5.5V, $I_{REF} = 0$		1.98		2.02	V
FAULT DETECTION							
Output Overvoltage Trip Threshold		MAX8716/MAX8717/N	1AX8756 only	11		19	%
Output Undervoltage-Protection Trip Threshold		With respect to error-c	comparator threshold	65		75	%
PGOOD_ Lower Trip Threshold		With respect to error-o hysteresis = 1%	comparator threshold,	-12.5		-8.0	%
PGOOD_ Output Low Voltage		I <sub>SINK</sub> = 4mA				0.4	V
GATE DRIVERS							
DH_ Gate-Driver On-Resistance	R <sub>DH</sub>	BST LX_ forced to 5	5V (Note 5)			5	Ω
DL_ Gate-Driver On-Resistance		DL_, high state				5	0
(Note 5)	RDL	DL_, low state				3	\$2
INPUTS AND OUTPUTS							
ON_ Input Voltage		Rising edge, hysteres	is = 225mV	1.2		2.2	V
			High	V <sub>CC</sub> - 0.2			v
Tri-Level Input Logic		SKIP1, SKIP2, FSEL	REF	1.7		2.3	
			GND			0.5	

**Note 2:** When the inductor is in continuous conduction, the output voltage will have a DC regulation level lower than the error-comparator threshold by 50% of the ripple. In discontinuous conduction, the output voltage will have a DC regulation level higher than the error-comparator threshold by 50% of the ripple.

Note 3: Default setting for the MAX8716.

**Note 4:** Specifications are guaranteed by design, not production tested.

Note 5: Production testing limitations due to package handling require relaxed maximum on-resistance specifications for the thin QFN package.

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**Note 6:** Specifications from 0°C to -40°C are guaranteed by design, not production tested.

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MAX8716/MAX8717/MAX8756/MAX8757

(Circuit of Figure 1, MAX8717, VIN = 12V, VDD = VCC = 5V, SKIP\_ = GND, FSEL = REF, TA = +25°C, unless otherwise noted.)

**Typical Operating Characteristics** 



**MAX8716/MAX8717/MAX8756/MAX875**7

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### \_Typical Operating Characteristics (continued)

(Circuit of Figure 1, MAX8717,  $V_{IN} = 12V$ ,  $V_{DD} = V_{CC} = 5V$ ,  $\overline{SKIP}$  = GND, FSEL = REF,  $T_A = +25^{\circ}C$ , unless otherwise noted.)





### **Typical Operating Characteristics (continued)**

(Circuit of Figure 1, MAX8717, V<sub>IN</sub> = 12V, V<sub>DD</sub> = V<sub>CC</sub> = 5V, SKIP\_ = GND, FSEL = REF, T<sub>A</sub> = +25°C, unless otherwise noted.)



### \_Pin Description

F	PIN								
MAX8716	MAX8717/ MAX8756/ MAX8757	NAME	FUNCTION						
1	1	Vcc	Analog Supply Input. series 20Ω resistor. By	Connect to the system supply voltage (+4.5 ypass $V_{CC}$ to AGND with a 1µF or greater co	V to +5.5V) through a eramic capacitor.				
2	2	SKIP1	Low-Noise Mode Cont (pulse-skipping) opera for low-noise mode.	Low-Noise Mode Control for SMPS1. Connect SKIP1 to GND for normal Idle Mode (pulse-skipping) operation or to V <sub>CC</sub> for PWM mode (fixed frequency). Connect to REF for low-noise mode.					
3	3	REF	2.0V Reference Voltag capacitor. The referen accuracy according to <i>Characteristics</i> ). The r	2.0V Reference Voltage Output. Bypass REF to AGND with a $0.1\mu$ F or greater ceramic capacitor. The reference can source up to $50\mu$ A. Loading REF degrades output voltage accuracy according to the REF load-regulation error (see the <i>Typical Operating Characteristics</i> ). The reference shuts down when both ON1 and ON2 are low.					
4	4	SKIP2	Low-Noise Mode Cont (pulse-skipping) opera for low-noise mode.	Low-Noise Mode Control for SMPS2. Connect $\overline{SKIP2}$ to GND for normal Idle Mode (pulse-skipping) operation or to V <sub>CC</sub> for PWM mode (fixed frequency). Connect to REF for low-noise mode.					
			Frequency Select Input. This four-level logic input sets the controller's switching frequency.						
	5	EQEI	FSEL	MAX8717/MAX8757 (kHz)	MAX8756 (kHz)				
_	5	FJEL	V <sub>CC</sub>	500	400				
			REF	300	300				
			GND	200	250				
5	6	ON1	SMPS1 Enable Input. SMPS1.	Drive ON1 high to enable SMPS1. Drive ON	11 low to shut down				
6	7	ON2	SMPS2 Enable Input. SMPS2.	Drive ON1 high to enable SMPS2. Drive ON	12 low to shut down				
	8	ILIM2	SMPS2 Peak Current-L default 50mV current-li CSH2 and CSL2 is pre The logic threshold for	imit Threshold Adjustment. Connect ILIM2 to mit threshold. In adjustable mode, the curren cisely 1/10 the voltage seen at ILIM2 over a 5 switchover to the 50mV default value is appro	V <sub>CC</sub> to enable the t-limit threshold across i00mV to 2.0V range. pximately V <sub>CC</sub> - 1V.				
7	9	PGOOD2	SMPS2 Open-Drain Po 10% below its regulation	ower-Good Output. PGOOD2 is low when S ion threshold, during soft-start, and in shutd	MPS2 is more than own.				
8	10	FB2	Feedback Input for SM MAX8716/MAX8717/M FB2 regulates to 1V.	MPS2. Connect FB2 to V <sub>CC</sub> for fixed 5V outp MAX8757, or a fixed 1.8V for the MAX8756. I	out for the n adjustable mode,				
9	11	CSL2	Negative Current-Sense current-sense elemen	se Input for SMPS2. Connect to the negative t. Figure 8 describes two different current-se	e terminal of the ensing options.				
10	12	CSH2	Positive Current-Sense sense element. Figure	e Input for SMPS2. Connect to the positive to 8 describes two different current-sensing of	erminal of the current-				
11	13	BST2	Boost Flying Capacitor Connection for SMPS2. Connect to an external capacitor and diode as shown in Figure 1. An optional resistor in series with BST2 allows the DH2 turn-on current to be adjusted.						
12	14	DH2	High-Side Gate-Driver	r Output for SMPS2. DH2 swings from LX2 to	o BST2.				
13	15	LX2	Inductor Connection for is the lower supply rai	or SMPS2. Connect LX2 to the switched sid I for the DH2 high-side gate driver.	e of the inductor. LX2				



### **Pin Description (continued)**

PIN			
MAX8716	MAX8717/ MAX8756/ MAX8757	NAME	FUNCTION
14	16	DL2	Low-Side Gate-Driver Output for SMPS2. DL2 swings from PGND to VDD.
15	17	V <sub>DD</sub>	Supply Voltage Input for the DL_ Gate Drivers. Connect to a 5V supply.
16	—	GND	Power and Analog Ground. Connect backside pad to GND.
	18	PGND	Power Ground
—	19	AGND	Analog Ground. Connect backside pad to AGND.
17	20	DL1	Low-Side Gate-Driver Output for SMPS1. DL1 swings from PGND to $V_{DD}$ .
18	21	LX1	Inductor Connection for SMPS1. Connect LX1 to the switched side of the inductor. LX1 is the lower supply rail for the DH1 high-side gate driver.
19	22	DH1	High-Side Gate-Driver Output for SMPS1. DH1 swings from LX1 to BST1.
20	23	BST1	Boost Flying Capacitor Connection for SMPS1. Connect to an external capacitor and diode as shown in Figure 1. An optional resistor in series with BST1 allows the DH1 turn- on current to be adjusted.
21	24	CSH1	Positive Current-Sense Input for SMPS1. Connect to the positive terminal of the current- sense element. Figure 8 describes two different current-sensing options.
22	25	CSL1	Negative Current-Sense Input for SMPS1. Connect to the negative terminal of the current-sense element. Figure 8 describes two different current-sensing options.
23	26	FB1	Feedback Input for SMPS1. Connect FB1 to $V_{CC}$ for fixed 3.3V output for the MAX8716/MAX8717/MAX8757, or a fixed 1.5V for the MAX8756. In adjustable mode, FB1 regulates to 1V.
24	27	PGOOD1	SMPS1 Open-Drain Power-Good Output. PGOOD1 is low when SMPS1 is more than 10% below its regulation threshold, during soft-start, and in shutdown.
_	28	ILIM1	SMPS1 Peak Current-Limit Threshold Adjustment. Connect ILIM1 to V <sub>CC</sub> to enable the default 50mV current-limit threshold. In adjustable mode, the current-limit threshold across CSH1 and CSL1 is precisely 1/10 the voltage seen at ILIM1 over a 500mV to 2.0V range. The logic threshold for switchover to the 50mV default value is approximately V <sub>CC</sub> - 1V.
EP	EP	EP	Exposed Pad. Connect exposed backside pad to analog ground.

### **Detailed Description**

The MAX8716/MAX8717/MAX8756/MAX8757 Standard Application Circuit (Figure 1) generates the 5V/5A and 3.3V/5A typical of the main supplies in notebook computers. The input supply range is 6V to 24V. See Table 1 for component selections, while Table 2 lists the component manufacturers.

The MAX8716/MAX8717/MAX8756/MAX8757 contain two interleaved fixed-frequency, step-down controllers designed for low-voltage power supplies. The optimal interleaved architecture guarantees out-of-phase operation, which reduces the input capacitor ripple.

### SMPS 5V Bias Supply (Vcc and VDD)

The MAX8716/MAX8717/MAX8756/MAX8757 switchmode power supplies (SMPS) require a 5V bias supply in addition to the high-power input supply (battery or AC adapter). VDD is the power rail for the MOSFET gate drive, and V<sub>CC</sub> is the power rail for the IC. Connect the external 4.5V to 5.5V supply directly to VDD and connect V<sub>DD</sub> to V<sub>CC</sub> through an RC filter, as shown in Figure 1. The maximum supply current required is:

 $I_{BIAS} = I_{CC} + f_{SW} (Q_{G(NL1)} + Q_{G1(NH1)} + Q_{G2(NL2)} +$ 

#### $Q_{G2(NH2)} = 1.3 \text{mA to } 40 \text{mA}$

where I<sub>CC</sub> is 1.3mA, f<sub>SW</sub> is the switching frequency, and QG are the MOSFET data sheet's total gatecharge specification limits at  $V_{GS} = 5V$ .

MAX8716/MAX8717/MAX8756/MAX8757



Figure 1. Standard Application Circuit

MAX8716/MAX8717/MAX8756/MAX8757

### Table 1. Component Selection for Standard Applications

COMPONENT	MAX8716/MAX8717/MAX8757	MAX8716/MAX8717/MAX8757	MAX8756
	5V/5A, 3.3V/5A, 300kHz	5V/5A, 3.3V/5A, 500kHz	1.8V/5A, 1.5V/5A, 300kHz
Input Voltage	$V_{IN} = 7V$ to 24V	$V_{IN} = 7V$ to 24V	$V_{IN} = 7V$ to 24V
CIN, Input Capacitor	(2) 10µF, 25V	(2) 10µF, 25V	(2) 10µF, 25V
	Taiyo Yuden TMK432BJ106KM	Taiyo Yuden TMK432BJ106KM	Taiyo Yuden TMK432BJ106KM
COUT1, Output Capacitor	220 $\mu$ F, 4V, 25m $\Omega$	150 $\mu$ F, 4V, 25m $\Omega$	220μF, 4V, 18mΩ
	low-ESR capacitor,	low-ESR capacitor,	low-ESR capacitor,
	SANYO 4TPE220M	SANYO 4TPE150M	SANYO 4TPE220MIC2
C <sub>OUT2</sub> , Output Capacitor	150μF, 6.3V, 25m $\Omega$	100 $\mu$ F, 6.3V, 25m $\Omega$	220μF, 4V, 18mΩ
	low-ESR capacitor,	low-ESR capacitor,	low-ESR capacitor,
	SANYO 6TPE150M	SANYO 6TPE100M	SANYO 4TPE220MIC2
N <sub>H</sub> _ High-Side MOSFET	Fairchild Semiconductor	Fairchild Semiconductor	Fairchild Semiconductor
	FDS6612A	FDS6612A	FDS6612A
	International Rectifier	International Rectifier	International Rectifier
	IRF7807V	IRF7807V	IRF7807V
N <sub>L_</sub> Low-Side MOSFET	Fairchild Semiconductor	Fairchild Semiconductor	Fairchild Semiconductor
	FDS6670S	FDS6670S	FDS6670S
	International Rectifier	International Rectifier	International Rectifier
	IRF7807VD1	IRF7807VD1	IRF7807VD1
DL_ Schottky Rectifier	Nihon EC21QS03L	Nihon EC21QS03L	Nihon EC21QS03L
(if needed)	2A, 30V, 0.45Vf	2A, 30V, 0.45Vf	2A, 30V, 0.45Vf
L_ Inductor	5.7µH	3.9µH	3.1µH
	Sumida CDEP105-5R7NC	Sumida CDRH124-3R9NC	Sumida CDRH125-3R1NC
Rsense_	$7m\Omega \pm 1\% 0.5W$ resistor	7mΩ ±1% 0.5W resistor	7mΩ ±1% 0.5W resistor
	IRC LR2010-01-R007F or	IRC LR2010-01-R007F or	IRC LR2010-01-R007F or
	Dale WSL-2010-R007F	Dale WSL-2010-R007F	Dale WSL-2010-R007F

### **Table 2. Component Suppliers**

SUPPLIER	WEBSITE
AVX	www.avx.com
Central Semiconductor	www.centralsemi.com
Coilcraft	www.coilcraft.com
Coiltronics	www.coiltronics.com
Fairchild Semiconductor	www.fairchildsemi.com
International Rectifier	www.irf.com
KEMET	www.kemet.com
Panasonic	www.panasonic.com/industrial
SANYO	www.secc.co.jp
Sumida	www.sumida.com
Taiyo Yuden	www.t-yuden.com
TDK	www.component.tdk.com
ТОКО	www.tokoam.com
Vishay (Dale, Siliconix)	www.vishay.com

#### **Reference (REF)**

The 2V reference is accurate to  $\pm 1.5\%$  over temperature and load, making REF useful as a precision system reference. Bypass REF to GND with a  $0.1\mu$ F or greater ceramic capacitor. The reference sources up to  $50\mu$ A and sinks  $10\mu$ A to support external loads.

### **SMPS Detailed Description**

Power-on reset (POR) occurs when V<sub>CC</sub> rises above approximately 2V, resetting the undervoltage, overvoltage, and thermal-shutdown fault latches. The POR circuit also ensures that the low-side drivers are driven high until the SMPS controllers are activated. The V<sub>CC</sub> input undervoltage-lockout (UVLO) circuitry inhibits switching if V<sub>CC</sub> is below the V<sub>CC</sub> UVLO threshold.

An internal soft-start gradually increases the regulation voltage during startup to reduce the input surge currents (see the startup waveforms in the *Typical Operating Characteristics*).







#### SMPS Enable Controls (ON1, ON2)

ON1 and ON2 provide independent control of output soft-start and soft-shutdown. This allows flexible control of startup and shutdown sequencing. The outputs can be started simultaneously, sequentially, or independently. To provide sequential startup, connect ON\_ of one regulator to PGOOD\_ of the other. For example, with ON1 connected to PGOOD2, OUT1 soft-starts after OUT2 is in regulation. Drive ON\_ low to clear the overvoltage, undervoltage, and thermal fault latches.

#### Soft-Start and Soft-Shutdown

Soft-start begins when ON\_ is driven high and REF is in regulation. During soft-start, the output is ramped up

from 0V to the final set voltage in 2ms. This reduces inrush current and provides a predictable ramp-up time for power sequencing.

Soft-shutdown begins after ON\_ goes low, an output undervoltage fault occurs, or a thermal fault occurs. The two outputs are independent. A fault at one output does not trigger shutdown of the other. During softshutdown the output is ramped down to 0V in 4ms, reducing negative inductor currents that can cause negative voltages on the output. At the end of soft-shutdown, DL\_ is driven high until startup is again triggered by a rising edge of ON\_. The reference is turned off when both outputs have been shut down.



#### Fixed-Frequency, Current-Mode PWM Controller

The heart of each current-mode PWM controller is a multi-input, open-loop comparator that sums two signals: the output-voltage error signal with respect to the reference voltage and the slope-compensation ramp (Figure 3). The MAX8716/MAX8717/MAX8756/MAX8757 use a direct-summing configuration, approaching ideal cycle-to-cycle control over the output voltage without a traditional error amplifier and the phase shift associated with it. The MAX8716/MAX8717/MAX8756/MAX8757 use a relatively low loop gain, allowing the use of low-cost output capacitors. The low loop gain results in the 0.1% typical load-regulation error and helps reduce the output capacitor size and cost by shifting the unity-gain crossover frequency to a lower level.

#### Frequency Selection (FSEL)

The FSEL input selects the PWM mode switching frequency. Table 3 shows the switching frequency based on the FSEL connection. High-frequency operation optimizes the application for the smallest component size, trading off efficiency due to higher switching losses. This may be acceptable in ultra-portable devices where the load currents are lower. Low-frequency operation offers the best overall efficiency at the expense of component size and board space.

#### Forced-PWM Mode

To maintain low ripple fixed-frequency operation, drive  $\overline{SKIP}$  high to put the output into forced-PWM mode. This disables the zero-crossing comparator and allows negative inductor current. During forced-PWM mode,



Figure 3. PWM-Controller Functional Diagram

the switching frequency remains constant and the no-load supply current is typically between 8mA and 20mA per phase, depending on external MOSFETs and switching frequency.

Light-Load Operation Control (SKIP\_) The MAX8716/MAX8717/MAX8756/MAX8757 include SKIP\_ inputs that enable the corresponding outputs to operate in discontinuous mode. Connect SKIP\_ to GND or REF as shown in Table 4 to enable or disable the zero-crossing comparators of either controller. When the zero-crossing comparator is enabled, the controller forces DL\_ low when the current-sense inputs detect zero inductor current. This keeps the inductor from discharging the output capacitors and forces the controller to skip pulses under light-load conditions to avoid overcharging the output. During skip mode, the  $V_{\Box \Box}$  current consumption is reduced and efficiency is improved. During low-noise skip mode, the no-load ripple amplitude is two times smaller and the no-load switching frequency is four times higher, although the light-load efficiency is somewhat lower.

 Table 3. FSEL Configuration Table

FSEL	MAX8717/ MAX8757 (kHz)	MAX8756 (kHz)
V <sub>CC</sub>	500	400
REF	300	300
GND	200	250

#### Idle Mode Current-Sense Threshold

When pulse-skipping mode is enabled, the on-time of the step-down controller terminates when the output voltage exceeds the feedback threshold and when the current-sense voltage exceeds the Idle Mode currentsense threshold. Under light-load conditions, the ontime duration depends solely on the Idle Mode current-sense threshold  $(SKIP_ = GND)$ , which is 20% of the full-load current-limit threshold set by ILIM\_, or the low-noise current-sense threshold ( $\overline{SKIP}$  = REF), which is 10% for the MAX8716/MAX8717/MAX8757 and 5% for the MAX8756 of the full-load current-limit threshold set by ILIM\_. This forces the controller to source a minimum amount of power with each cycle. To avoid overcharging the output, another on-time cannot begin until output voltage drops below the feedback threshold. Since the zero-crossing comparator prevents the switching regulator from sinking current, the controller must skip pulses. Therefore, the controller regulates the valley of the output ripple under light-load conditions.



Figure 4. Pulse-Skipping/Discontinuous Crossover Point

#### Automatic Pulse-Skipping Crossover

In skip mode, an inherent automatic switchover to PFM takes place at light loads (Figure 4). This switchover is affected by a comparator that truncates the low-side switch on-time at the inductor current's zero crossing. The zero-crossing comparator senses the inductor current across CSH\_ and CSL\_. Once VCSH - VCSL\_ drops below the 3mV zero-crossing, current-sense threshold, the comparator forces DL\_ low (Figure 3). This mechanism causes the threshold between pulse-skipping PFM and nonskipping PWM operation to coincide with the boundary between continuous and discontinuous inductor-current operation (also known as the "critical conduction" point). The load-current level at which PFM/PWM crossover occurs, I<sub>LOAD(SKIP)</sub>, is determined by:

$$I_{LOAD(SKIP)} = \frac{(V_{IN} - V_{OUT})V_{OUT}}{2LV_{IN}f_{OSC}}$$

The switching waveforms may appear noisy and asynchronous when light loading causes pulse-skipping operation, but this is a normal operating condition that results in high light-load efficiency. Trade-offs in PFM noise vs. light-load efficiency are made by varying the inductance. Generally, low inductance produces a broader efficiency vs. load curve, while higher values result in higher full-load efficiency (assuming that the coil resistance remains fixed) and less output voltage ripple. Penalties for using higher inductor values include larger physical size and degraded load-transient response (especially at low input-voltage levels).

#### **Output Voltage**

DC output accuracy specifications in the *Electrical Characteristics* refer to the error comparator's threshold. When the inductor continuously conducts, the MAX8716/MAX8717/MAX8756/MAX8757 regulate the peak of the output ripple, so the actual DC output voltage is lower than the slope-compensated trip level by 50% of the output ripple voltage. For PWM operation (continuous conduction), the output voltage is accurately defined by the following equation:

#### Table 4. SKIP\_ Configuration Table

SKIP_	MODE COMMENTS		
V <sub>CC</sub>	Forced-PWM mode	Fixed-frequency operation. Constant output ripple voltage. Able to source and sink current.	
GND	Skip mode	High efficiency at light loads. Source-only applications.	
REF	Low-noise skip mode	Good efficiency at light loads. $(V_{IDLE} / V_{LN})$ times smaller no-load ripple and $(V_{IDLE} / V_{LN})^2$ times higher frequency compared with skip mode. Source-only applications.	

#### Table 5. Operating Modes Truth Table

$$V_{OUT(PWM)} = V_{NOM} \left( 1 - \frac{A_{SLOPE}(V_{IN} - V_{NOM})}{V_{IN}} \right) - \left( \frac{V_{RIPPLE}}{2} \right)$$

where  $V_{NOM}$  is the nominal output voltage,  $A_{SLOPE}$  equals 1%, and  $V_{RIPPLE}$  is the output ripple voltage ( $V_{RIPPLE} = R_{ESR} \times \Delta I_{INDUCTOR}$  as described in the *Output Capacitor Selection* section).

In discontinuous conduction ( $I_{OUT} < I_{LOAD(SKIP)}$ ), the MAX8716/MAX8717/MAX8756/MAX8757 regulate the valley of the output ripple, so the output voltage has a DC regulation level higher than the error-comparator threshold. For PFM operation (discontinuous conduction), the output voltage is approximately defined by the following equation:

$$V_{OUT(PFM)} = V_{NOM} + \frac{1}{2} \left( \frac{f_{SW}}{f_{OSC}} \right) I_{IDLE} R_{ESR}$$

where  $V_{NOM}$  is the nominal output voltage, fOSC is the maximum switching frequency set by the internal oscillator, fSW is the actual switching frequency, and I<sub>IDLE</sub> is the Idle Mode inductor current when pulse skipping.

MODE	CONDITION	COMMENT
Power-Up	V <sub>CC</sub> UVLO	DL_ tracks V <sub>CC</sub> as V <sub>CC</sub> rises from 0V to +5V. When ON_ is low, DL_ tracks V <sub>CC</sub> as V <sub>CC</sub> falls. When ON_ is high, DL_ is forced low as V <sub>CC</sub> falls below the $3.95V$ (typ) falling UVLO threshold. DL_ is forced high when V <sub>CC</sub> falls below 1V (typ).
Run	ON1 or ON2 enabled	Normal operation.
Output Overvoltage Protection (OVP) MAX8716/MAX8717/ MAX8756 Only	Either output > 115% of nominal level	When the overvoltage (OV) comparator trips, the faulted side sets the OV latch, forcing PGOOD_ low and DL_ high. The other controller is not affected. The OV latch is cleared by cycling V <sub>CC</sub> below 1V or cycling the respective ON_ pin.
Output Undervoltage Protection (UVP)	Either output < 70% of nominal level, UVP is enabled 6144 clock cycles (1/f <sub>OSC</sub> ) after the output is enabled (ON_ going high)	When the undervoltage (UV) comparator trips, the faulted side sets the UV latch, forcing PGOOD_ low and initiating the soft-shutdown sequence by pulsing only DL DL_ goes high after soft-shutdown. The other controller is not affected. The UV latch is cleared by cycling V <sub>CC</sub> below 1V or cycling the respective ON_ pin.
Shutdown	ON1 and ON2 are driven low	DL_ stays high after soft-shutdown is completed. All circuitry is shut down.
Thermal Shutdown	T <sub>J</sub> > +160°C	Exited by POR or cycling ON1 and ON2. DL1 and DL2 remain high.





Figure 5. Dual Mode Feedback Decoder

#### Adjustable/Fixed Output Voltages (Dual-Mode Feedback)

Connect FB1 and FB2 to V<sub>CC</sub> to enable the fixed SMPS output voltages (3.3V and 5V, respectively, for the MAX8716/MAX8717/MAX8757, and 1.5V and 1.8V for the MAX8756, respectively), set by a preset, internal resistive voltage-divider connected between CSL\_ and analog ground. See Figure 5. Connect a resistive voltage-divider at FB\_ between CSL\_ and GND to adjust the respective output voltage between 1V and 5.5V. Choose R2 (resistance from FB to AGND) to be approximately 10k $\Omega$  and solve for R1 (resistance from OUT to FB) using the equation:

$$R1 = R2 \left( \frac{V_{OUT_{-}}}{V_{FB_{-}}} - 1 \right)$$

where  $V_{FB} = 1V$  nominal.

#### **Current-Limit Protection (ILIM\_)**

The current-limit circuit uses differential current-sense inputs (CSH\_ and CSL\_) to limit the peak inductor current. If the magnitude of the current-sense signal exceeds the current-limit threshold, the PWM controller turns off the high-side MOSFET (Figure 3). At the next rising edge of the internal oscillator, the PWM controller does not initiate a new cycle unless the current-sense signal drops below the current-limit threshold. The actual maximum load current is less than the peak current-limit threshold by an amount equal to half of the



inductor ripple current. Therefore, the maximum load capability is a function of the current-sense resistance, inductor value, switching frequency, and duty cycle (Vout / VIN).

In forced-PWM mode, the MAX8716/MAX8717/ MAX8756/MAX8757 also implement a negative current limit to prevent excessive reverse inductor currents when  $V_{OUT}$  is sinking current. The negative current-limit threshold is set to approximately -120% of the positive current limit and tracks the positive current limit when ILIM is adjusted.

Connect ILIM\_ to V<sub>CC</sub> for the 50mV default threshold, or adjust the current-limit threshold with an external resistor-divider at ILIM\_. Use a 2µA to 20µA divider current for accuracy and noise immunity. The current-limit threshold adjustment range is from 50mV to 200mV. In the adjustable mode, the current-limit threshold voltage equals precisely 1/10 the voltage seen at ILIM\_. The logic threshold for switchover to the 50mV default value is approximately V<sub>CC</sub> - 1V.

Carefully observe the PCB layout guidelines to ensure that noise and DC errors do not corrupt the differential current-sense signals seen by CSH\_ and CSL\_. Place the IC close to the sense resistor with short, direct traces, making a Kelvin-sense connection to the current-sense resistor.

#### **MOSFET Gate Drivers (DH\_, DL\_)**

The DH\_ and DL\_ drivers are optimized for driving moderate-sized high-side, and larger low-side power MOSFETs. This is consistent with the low duty factor seen in notebook applications, where a large  $V_{IN}$  -  $V_{OUT}$  differential exists. The high-side gate drivers (DH\_) source and sink 2A, and the low-side gate drivers (DL\_) source 1.7A and sink 3.3A. This ensures robust gate drive for high-current applications. The DH\_ floating high-side MOSFET drivers are powered by diode-capacitor charge pumps at BST\_ (Figure 6) while the DL\_ synchronous-rectifier drivers are powered directly by the external 5V supply (VDD).

Adaptive dead-time circuits monitor the DL\_ and DH\_ drivers and prevent either FET from turning on until the other is fully off. The adaptive driver dead-time allows operation without shoot-through with a wide range of MOSFETs, minimizing delays and maintaining efficiency. There must be a low-resistance, low-inductance path from the DL\_ and DH\_ drivers to the MOSFET gates for the adaptive dead-time circuits to work properly; otherwise, the sense circuitry in the MAX8716/MAX8717/MAX8756/MAX8757 interprets the MOSFET gates as "off" while charge actually remains. Use very short, wide traces (50 mils to 100 mils wide if the MOSFET is 1 in from the driver).

The internal pulldown transistor that drives DL\_ low is robust, with a 0.6 $\Omega$  (typ) on-resistance. This helps prevent DL\_ from being pulled up due to capacitive coupling from the drain to the gate of the low-side MOSFETs when the inductor node (LX\_) quickly switches from ground to VIN. Applications with high input voltages and long inductive driver traces may require additional gate-to-source capacitance to ensure fast-rising LX\_ edges do not pull up the low-side MOSFETs gate, causing shoot-through currents. The capacitive coupling between LX\_ and DL\_ created by the MOSFET's gate-to-drain capacitance (CRSS), gate-to-source capacitance (CISS - CRSS), and additional board parasitics should not exceed the following minimum threshold:

$$V_{GS(TH)} > V_{IN} \left( \frac{C_{RSS}}{C_{ISS}} \right)$$

Variation of the threshold voltage may cause problems in marginal designs. Alternatively, adding a resistor less than  $10\Omega$  in series with BST\_ may remedy the problem by increasing the turn-on time of the high-side MOSFET without degrading the turn-off time (Figure 6).



Figure 6. Optional Gate-Driver Circuitry

#### **Power-Good Output (PGOOD\_)**

PGOOD\_ is the open-drain output of a comparator that continuously monitors each SMPS output voltage for overvoltage and undervoltage conditions. PGOOD\_ is actively held low in shutdown (ON\_ = GND), soft-start, and soft-shutdown. Once the analog soft-start terminates, PGOOD\_ becomes high impedance as long as the output is above 90% of the nominal regulation voltage set by FB\_. PGOOD\_ goes low once the output drops 10% below its nominal regulation point, an output overvoltage fault occurs, or ON\_ is pulled low. For a logic-level PGOOD\_ output voltage, connect an external pullup resistor between PGOOD\_ and +5V or +3.3V. A 100k $\Omega$  pullup resistor works well in most applications.

#### Fault Protection

#### Output Overvoltage Protection (MAX8716/MAX8717/MAX8756 Only)

If the output voltage of either SMPS rises above 115% of its nominal regulation voltage, the corresponding controller sets its overvoltage fault latch, pulls PGOOD\_low, and forces DL\_ high for the corresponding SMPS controller. The other controller is not affected. If the condition that caused the overvoltage persists (such as a shorted high-side MOSFET), the battery fuse will blow. Cycle V<sub>CC</sub> below 1V or toggle ON\_ to clear the overvoltage fault latch and restart the SMPS controller.



Figure 7. Power-Good and Fault Protection



#### Output Undervoltage Protection

If the output voltage of either SMPS falls below 70% of its regulation voltage, the corresponding controller sets its undervoltage fault latch, pulls PGOOD\_ low, and begins soft-shutdown for the corresponding SMPS controller by pulsing DL\_. DH\_ remains off during the soft-shutdown sequence initiated by an unvervoltage fault. The other controller is not affected. After soft-shutdown has completed, the MAX8716/MAX8717/MAX8756/MAX8757 force DL\_ high and DH\_ low. Cycle V<sub>CC</sub> below 1V or toggle ON\_ to clear the undervoltage fault latch and restart the SMPS controller.

#### VCC POR and UVLO

Power-on reset (POR) occurs when V<sub>CC</sub> rises above approximately 2V, resetting the fault latch and preparing the PWM for operation. V<sub>CC</sub> undervoltage-lockout (UVLO) circuitry inhibits switching, forces PGOOD\_low, and forces the DL\_ gate drivers low.

If V<sub>CC</sub> drops low enough to trip the UVLO comparator while ON\_ is high, the MAX8716/MAX8717/MAX8756/ MAX8757 immediately force DH\_ and DL\_ low on both controllers. The output discharges to 0V at a rate dependent on the load and the total output capacitance. This prevents negative output voltages, eliminating the need for a Schottky diode to GND at the output.

#### Thermal Fault Protection

The MAX8716/MAX8717/MAX8756/MAX8757 feature a thermal fault-protection circuit. When the junction temperature rises above +160°C, a thermal sensor sets the fault latches, pulls PGOOD low, and shuts down both SMPS controllers using the soft-shutdown sequence (see the *Sort-Start and Soft-Shutdown* section). Cycle V<sub>CC</sub> below 1V or toggle ON1 and ON2 to clear the fault latches and restart the controllers after the junction temperature cools by 15°C.

#### Design Procedure

Firmly establish the input voltage range and maximum load current before choosing a switching frequency and inductor operating point (ripple-current ratio). The primary design trade-off lies in choosing a good switching frequency and inductor operating point, and the following four factors dictate the rest of the design:

 Input Voltage Range. The maximum value (VIN(MAX)) must accommodate the worst-case, high AC-adapter voltage. The minimum value (VIN(MIN)) must account for the lowest battery voltage after drops due to connectors, fuses, and battery selector switches. If there is a choice at all, lower input voltages result in better efficiency.

- Maximum Load Current. There are two values to consider. The peak load current (I<sub>LOAD</sub>(MAX)) determines the instantaneous component stresses and filtering requirements and thus drives output capacitor selection, inductor saturation rating, and the design of the current-limit circuit. The continuous load current (I<sub>LOAD</sub>) determines the thermal stresses and thus drives the selection of input capacitors, MOSFETs, and other critical heat-contributing components.
- Switching Frequency. This choice determines the basic trade-off between size and efficiency. The optimal frequency is largely a function of maximum input voltage, due to MOSFET switching losses that are proportional to frequency and V<sub>IN</sub><sup>2</sup>. The optimum frequency is also a moving target, due to rapid improvements in MOSFET technology that are making higher frequencies more practical.
- Inductor Operating Point. This choice provides trade-offs between size vs. efficiency and transient response vs. output ripple. Low inductor values provide better transient response and smaller physical size, but also result in lower efficiency and higher output ripple due to increased ripple currents. The minimum practical inductor value is one that causes the circuit to operate at the edge of critical conduction (where the inductor current just touches zero with every cycle at maximum load). Inductor values lower than this grant no further size-reduction benefit. The optimum operating point is usually found between 20% and 50% ripple current. When pulseskipping (SKIP low and light loads), the inductor value also determines the load-current value at which PFM/PWM switchover occurs.

#### Inductor Selection

The switching frequency and inductor operating point determine the inductor value as follows:

$$L = \frac{V_{OUT}(V_{IN} - V_{OUT})}{V_{IN} f_{OSC} I_{LOAD}(MAX) LIR}$$

For example:  $I_{LOAD(MAX)} = 5A$ ,  $V_{IN} = 12V$ ,  $V_{OUT} = 5V$ ,  $f_{OSC} = 300$ kHz, 30% ripple current or LIR = 0.3:

$$L = \frac{5V \times (12V - 5V)}{12V \times 300 \text{kHz} \times 5A \times 0.3} = 6.50 \mu\text{H}$$

Find a low-loss inductor having the lowest possible DC resistance that fits in the allotted dimensions. Most inductor manufacturers provide inductors in standard values, such as  $1.0\mu$ H,  $1.5\mu$ H,  $2.2\mu$ H,  $3.3\mu$ H, etc. Also



look for nonstandard values, which can provide a better compromise in LIR across the input voltage range. If using a swinging inductor (where the no-load inductance decreases linearly with increasing current), evaluate the LIR with properly scaled inductance values. For the selected inductance value, the actual peak-to-peak inductor ripple current ( $\Delta$ I<sub>INDUCTOR</sub>) is defined by:

$$\Delta I_{\text{INDUCTOR}} = \frac{V_{\text{OUT}}(V_{\text{IN}} - V_{\text{OUT}})}{V_{\text{IN}} f_{\text{OSC}} L}$$

Ferrite cores are often the best choice, although powdered iron is inexpensive and can work well at 200kHz. The core must be large enough not to saturate at the peak inductor current (IPEAK):

$$I_{\text{PEAK}} = I_{\text{LOAD}(\text{MAX})} + \frac{\Delta I_{\text{INDUCTOR}}}{2}$$

#### **Transient Response**

The inductor ripple current also impacts transientresponse performance, especially at low V<sub>IN</sub> - V<sub>OUT</sub> differentials. Low inductor values allow the inductor current to slew faster, replenishing charge removed from the output filter capacitors by a sudden load step. The total output voltage sag is the sum of the voltage sag while the inductor is ramping up and the voltage sag before the next pulse can occur:

$$V_{SAG} = \frac{L(\Delta I_{LOAD(MAX)})^{2}}{2C_{OUT}(V_{IN} \times D_{MAX} - V_{OUT})} + \frac{\Delta I_{LOAD(MAX)}(T - \Delta T)}{C_{OUT}}$$

where D<sub>MAX</sub> is maximum duty factor (see the *Electrical Characteristics*), T is the switching period (1 / f<sub>OSC</sub>), and  $\Delta$ T equals V<sub>OUT</sub> / V<sub>IN</sub> x T when in PWM mode, or L x 0.2 x I<sub>MAX</sub> / (V<sub>IN</sub> - V<sub>OUT</sub>) when in skip mode. The amount of overshoot during a full-load to no-load transient due to stored inductor energy can be calculated as:

$$V_{\text{SOAR}} \approx \frac{(\Delta I_{\text{LOAD}(\text{MAX})})^2 L}{2C_{\text{OUT}} V_{\text{OUT}}}$$

#### **Setting the Current Limit**

The minimum current-limit threshold must be great enough to support the maximum load current when the current limit is at the minimum tolerance value. The peak inductor current occurs at ILOAD(MAX) plus half the ripple current; therefore:  $I_{\text{LIMIT}} > I_{\text{LOAD}(\text{MAX})} + \left(\frac{\Delta I_{\text{INDUCTOR}}}{2}\right)$ 

where  $I_{LIMIT}$  equals the minimum current-limit threshold voltage divided by the current-sense resistance (RSENSE). For the 50mV default setting, the minimum current-limit threshold is 50mV.

Connect ILIM\_ to V<sub>CC</sub> for a default 50mV current-limit threshold. In adjustable mode, the current-limit threshold is precisely 1/10 the voltage seen at ILIM\_. For an adjustable threshold, connect a resistive divider from REF to analog ground (GND) with ILIM\_ connected to the center tap. The external 500mV to 2V adjustment range corresponds to a 50mV to 200mV current-limit threshold. When adjusting the current limit, use 1% tolerance resistors and a divider current of approximately 10 $\mu$ A to prevent significant inaccuracy in the current-limit tolerance.

The current-sense method (Figure 8) and magnitude determines the achievable current-limit accuracy and power loss. Typically, higher current-sense limits provide tighter accuracy, but also dissipate more power. Most applications employ a current-limit threshold ( $V_{LIM}$ ) of 50mV to 100mV, so the sense resistor can be determined by:

$$R_{SENSE} = V_{LIM} / I_{LIM}$$

For the best current-sense accuracy and overcurrent protection, use a 1% tolerance current-sense resistor between the inductor and output as shown in Figure 8a. This configuration constantly monitors the inductor current, allowing accurate current-limit protection.

Alternatively, high-power applications that do not require highly accurate current-limit protection may reduce the overall power dissipation by connecting a series RC circuit across the inductor (Figure 8b) with an equivalent time constant:

$$\frac{L}{R_L} \!=\! C_{EQ} \!\times\! R_{EQ}$$

where R<sub>L</sub> is the inductor's series DC resistance. In this configuration, the current-sense resistance equals the inductor's DC resistance (R<sub>SENSE</sub> = R<sub>L</sub>). Use the worst-case inductance and R<sub>L</sub> values provided by the inductor manufacturer, adding some margin for the inductance drop over temperature and load.



Figure 8. Current-Sense Configurations

#### **Output Capacitor Selection**

The output filter capacitor must have low enough equivalent series resistance (ESR) to meet output ripple and load-transient requirements, yet have high enough ESR to satisfy stability requirements. The output capacitance must be high enough to absorb the inductor energy while transitioning from full-load to no-load conditions without tripping the overvoltage fault protection. When using high-capacitance, low-ESR capacitors (see the *Output-Capacitor Stability Considerations* section), the filter capacitor's ESR dominates the output voltage ripple. So the output capacitor's size depends on the maximum ESR required to meet the output-voltage-ripple (VRIPPLE(P-P)) specifications:

#### $V_{RIPPLE(P-P)} = R_{ESRILOAD(MAX)}LIR$

In Idle Mode, the inductor current becomes discontinuous, with peak currents set by the idle-mode currentsense threshold ( $V_{IDLE} = 0.2V_{LIMIT}$ ). In Idle Mode, the no-load output ripple can be determined as follows:

$$V_{\text{RIPPLE}(P-P)} = \frac{V_{\text{IDLE}}R_{\text{ESR}}}{R_{\text{SENSE}}}$$

The actual capacitance value required relates to the physical size needed to achieve low ESR, as well as to the chemistry of the capacitor technology. Thus, the capacitor is usually selected by ESR and voltage rating rather than by capacitance value (this is true of tantalums, OS-CONs, polymers, and other electrolytics). When using low-capacity filter capacitors, such as ceramic capacitors, size is usually determined by the capacity needed to prevent VSAG and VSOAR from causing problems during load transients. Generally, once enough capacitance is added to meet the overshoot requirement, undershoot at the rising load edge is no longer a problem (see the VSAG and VSOAR equations in the Transient Response section). However, lowcapacity filter capacitors typically have high-ESR zeros that may effect the overall stability (see the Output-Capacitor Stability Considerations section).

#### **Output-Capacitor Stability Considerations**

Stability is determined by the value of the ESR zero relative to the switching frequency. The boundary of instability is given by the following equation:

$$f_{\text{ESR}} \leq \frac{f_{\text{SW}}}{\pi}$$

where:

$$f_{\rm ESR} = \frac{1}{2\pi R_{\rm ESR} C_{\rm OUT}}$$

For a typical 300kHz application, the ESR zero frequency must be well below 95kHz, preferably below 50kHz. Tantalum and OS-CON capacitors in widespread use at the time of publication have typical ESR zero frequencies of 25kHz. In the design example used for inductor selection, the ESR needed to support 25mV<sub>P-P</sub> ripple is 25mV/1.5A = 16.7m $\Omega$ . One 220µF/4V SANYO polymer (TPE) capacitor provides 15m $\Omega$  (max) ESR. This results in a zero at 48kHz, well within the bounds of stability.

For low input-voltage applications where the duty cycle exceeds 50% (V<sub>OUT</sub> / V<sub>IN</sub>  $\geq$  50%), the output ripple voltage should not be greater than twice the internal slope-compensation voltage:

#### VRIPPLE ≤ 0.02 × VOUT

where VRIPPLE equals  $\Delta I_{INDUCTOR} \times R_{ESR}$ . The worstcase ESR limit occurs when  $V_{IN} = 2 \times V_{OUT}$ , so the above equation can be simplified to provide the following boundary condition:

#### $RESR \le 0.04 \times L \times fOSC$

Do not put high-value ceramic capacitors directly across the feedback sense point without taking precautions to ensure stability. Large ceramic capacitors can have a high-ESR zero frequency and cause erratic, unstable operation. However, it is easy to add enough series resistance by placing the capacitors a couple of inches downstream from the feedback sense point, which should be as close as possible to the inductor.

Unstable operation manifests itself in two related but distinctly different ways: short/long pulses or cycle skipping resulting in a lower switching frequency. Instability occurs due to noise on the output or because the ESR is so low that there is not enough voltage ramp in the output voltage signal. This "fools" the error comparator into triggering too early or skipping a cycle. Cycle skipping is more annoying than harmful, resulting in nothing worse than increased output ripple. However, it can indicate the possible presence of loop instability due to insufficient ESR. Loop instability can result in oscillations at the output after line or load steps. Such perturbations are usually damped, but can cause the output voltage to rise above or fall below the tolerance limits.

The easiest method for checking stability is to apply a very fast zero-to-max load transient and carefully observe the output-voltage-ripple envelope for overshoot and ringing. It can help to simultaneously monitor the inductor current with an AC current probe. Do not allow more than one cycle of ringing after the initial step-response under/overshoot.

#### **Input Capacitor Selection**

The input capacitor must meet the ripple-current requirement (I<sub>RMS</sub>) imposed by the switching currents. For an out-of-phase regulator, the total RMS current in the input capacitor is a function of the load currents, the input currents, the duty cycles, and the amount of overlap as defined in Figure 9.

The 40/60 optimal interleaved architecture of the MAX8716/MAX8717/MAX8756/MAX8757 allows the input voltage to go as low as 8.3V before the duty cycles begin to overlap. This offers improved efficiency over a regular 180° out-of-phase architecture where the duty cycles begin to overlap below 10V. Figure 9



Figure 9. Input RMS Current

shows the input-capacitor RMS current vs. input voltage for an application that requires 5V/5A and 3.3V/5A. This shows the improvement of the 40/60 optimal interleaving over 50/50 interleaving and in-phase operation.

For most applications, nontantalum chemistries (ceramic, aluminum, or OS-CON) are preferred due to their resistance to power-up surge currents typical of systems with a mechanical switch or connector in series with the input. Choose a capacitor that has less than 10°C temperature rise at the RMS input current for optimal reliability and lifetime.

#### **Power MOSFET Selection**

Most of the following MOSFET guidelines focus on the challenge of obtaining high load-current capability when using high-voltage (> 20V) AC adapters. Low-current applications usually require less attention.

The high-side MOSFET (N<sub>H</sub>) must be able to dissipate the resistive losses plus the switching losses at both V<sub>IN(MIN)</sub> and V<sub>IN(MAX)</sub>. Ideally, the losses at V<sub>IN(MIN)</sub> should be roughly equal to the losses at V<sub>IN(MAX)</sub>, with lower losses in between. If the losses at V<sub>IN(MAX)</sub>, with lower losses in between. If the losses at V<sub>IN(MIN)</sub> are significantly higher, consider increasing the size of N<sub>H</sub>. Conversely, if the losses at V<sub>IN(MAX)</sub> are significantly higher, consider reducing the size of N<sub>H</sub>. If V<sub>IN</sub> does not vary over a wide range, optimum efficiency is achieved by selecting a high-side MOSFET (N<sub>H</sub>) that has conduction losses equal to the switching losses.

Choose a low-side MOSFET (N<sub>L</sub>) that has the lowest possible on-resistance (R<sub>DS(ON)</sub>), comes in a moderate-sized package (i.e., 8-pin SO, DPAK, or D<sup>2</sup>PAK), and is reasonably priced. Ensure that the MAX8716/MAX8717/MAX8756/MAX8757 DL\_ gate driver can supply sufficient current to support the gate charge and the current injected into the parasitic drainto-gate capacitor caused by the high-side MOSFET turning on; otherwise, cross-conduction problems may occur. Switching losses are not an issue for the lowside MOSFET since it is a zero-voltage switched device when used in the step-down topology.

#### **Power MOSFET Dissipation**

Worst-case conduction losses occur at the duty-factor extremes. For the high-side MOSFET ( $N_H$ ), the worst-case power dissipation due to resistance occurs at minimum input voltage:

$$PD(N_{H} RESISTIVE) = \frac{V_{OUT}}{V_{IN}} (I_{LOAD})^{2} R_{DS(ON)}$$

Generally, use a small high-side MOSFET to reduce switching losses at high input voltages. However, the RDS(ON) required to stay within package power-dissipation limits often limits how small the MOSFET can be.

The optimum occurs when the switching losses equal the conduction ( $R_{DS(ON)}$ ) losses. High-side switching losses do not become an issue until the input is greater than approximately 15V.

Calculating the power dissipation in high-side MOSFETs (N<sub>H</sub>) due to switching losses is difficult, since it must allow for difficult-to-quantify factors that influence the turn-on and turn-off times. These factors include the internal gate resistance, gate charge, threshold voltage, source inductance, and PCB layout characteristics. The following switching-loss calculation provides only a very rough estimate and is no substitute for breadboard evaluation, preferably including verification using a thermocouple mounted on N<sub>H</sub>:



where C<sub>OSS</sub> is the N<sub>H</sub>, MOSFET's output capacitance,  $Q_G(SW)^2$ , is the change needed to turn on the N<sub>H</sub> MOSFET, and I<sub>GATE</sub> is the peak gate-drive source/sink current (1A typ).

Switching losses in the high-side MOSFET can become a heat problem when maximum AC adapter voltages are applied, due to the squared term in the switching-loss equation (C x  $V_{IN}^2 x f_{SW}$ ). If the high-side MOSFET chosen for adequate RDS(ON) at low battery voltages becomes extraordinarily hot when subjected to  $V_{IN}(MAX)$ , consider choosing another MOSFET with lower parasitic capacitance.

For the low-side MOSFET (NL), the worst-case power dissipation always occurs at maximum battery voltage:

PD (N<sub>L</sub> RESISTIVE) = 
$$\left[1 - \left(\frac{V_{OUT}}{V_{IN(MAX)}}\right)\right] (I_{LOAD})^2 R_{DS(ON)}$$

The absolute worst case for MOSFET power dissipation occurs under heavy-overload conditions that are greater than  $I_{LOAD}(MAX)$  but are not high enough to exceed the current limit and cause the fault latch to trip. To protect against this possibility, "overdesign" the circuit to tolerate:

$$I_{LOAD} = I_{LIMIT} - \left(\frac{\Delta I_{INDUCTOR}}{2}\right)$$

where I<sub>LIMIT</sub> is the peak current allowed by the currentlimit circuit, including threshold tolerance and senseresistance variation. The MOSFETs must have a relatively large heatsink to handle the overload power dissipation.

Choose a Schottky diode (D<sub>L</sub>) with a forward-voltage drop low enough to prevent the low-side MOSFET's body diode from turning on during the dead time. As a general rule, select a diode with a DC current rating equal to 1/3 the load current. This diode is optional and can be removed if efficiency is not critical.

#### **Boost Capacitors**

The boost capacitors (C<sub>BST</sub>) must be selected large enough to handle the gate-charging requirements of the high-side MOSFETs. Typically,  $0.1\mu$ F ceramic capacitors work well for low-power applications driving medium-sized MOSFETs. However, high-current applications driving large, high-side MOSFETs require boost capacitors larger than  $0.1\mu$ F. For these applications, select the boost capacitors to avoid discharging the capacitor more than 200mV while charging the highside MOSFETs' gates:

$$C_{BST} = \frac{Q_{GATE}}{200 mV}$$

where Q<sub>GATE</sub> is the total gate charge specified in the high-side MOSFET's data sheet. For example, assume the FDS6612A n-channel MOSFET is used on the high side. According to the manufacturer's data sheet, a single FDS6612A has a maximum gate charge of 13nC (V<sub>GS</sub> = 5V). Using the above equation, the required boost capacitance would be:

$$C_{BST} = \frac{13nC}{100mV} = 0.065 \mu F$$

Selecting the closest standard value, this example requires a  $0.1\mu F$  ceramic capacitor.

#### **Applications Information**

#### **Duty-Cycle Limits**

#### Minimum Input Voltage

The minimum input operating voltage (dropout voltage) is restricted by the maximum duty-cycle specification (see the *Electrical Characteristics* table). For the best dropout performance, use the slowest switching-frequency setting (FSEL = GND). However, keep in mind that the transient performance gets worse as the step-down regulators approach the dropout voltage, so bulk output capacitance must be added (see the voltage sag and soar equations in the *Design Procedure* section). The absolute point of dropout occurs when the inductor current ramps down during the off-time ( $\Delta$ IDOWN) as much as it ramps up during the on-time

( $\Delta I_{UP}$ ). This results in a minimum operating voltage defined by the following equation:

$$V_{\text{IN(MIN)}} = V_{\text{OUT}} + V_{\text{CHG}} + h\left(\frac{1}{D_{\text{MAX}}} - 1\right)(V_{\text{OUT}} + V_{\text{DIS}})$$

where V<sub>CHG</sub> and V<sub>DIS</sub> are the parasitic voltage drops in the charge and discharge paths, respectively. A reasonable minimum value for h is 1.5, while the absolute minimum input voltage is calculated with h = 1.

#### Maximum Input Voltage

The MAX8716/MAX8717/MAX8756/MAX8757 controller includes a minimum on-time specification, which determines the maximum input operating voltage that maintains the selected switching frequency (see the *Electrical Characteristics* table). Operation above this maximum input voltage results in pulse-skipping operation, regardless of the operating mode selected by SKIP. At the beginning of each cycle, if the output voltage is still above the feedback threshold voltage, the controller does not trigger an on-time pulse, effectively skipping a cycle. This allows the controller to maintain regulation above the maximum input voltage, but forces the controller to effectively operate with a lower switching frequency. This results in an input threshold voltage at which the controller begins to skip pulses (VIN(SKIP)):

$$V_{\rm IN(SKIP)} = V_{\rm OUT} \left( \frac{1}{f_{\rm OSC} t_{\rm ON(MIN)}} \right)$$

where fOSC is the switching frequency selected by FSEL.

#### **PCB Layout Guidelines**

Careful PCB layout is critical to achieving low switching losses and clean, stable operation. The switching power stage requires particular attention (Figure 10). If possible, mount all the power components on the top side of the board, with their ground terminals flush against one another. Follow these guidelines for good PCB layout:

- Keep the high-current paths short, especially at the ground terminals. This practice is essential for stable, jitter-free operation.
- Keep the power traces and load connections short. This practice is essential for high efficiency. Using thick copper PCBs (2oz vs. 1oz) can enhance full-load efficiency by 1% or more. Correctly routing PCB traces is a difficult task that must be approached in terms of fractions of centimeters, where a single m $\Omega$  of excess trace resistance causes a measurable efficiency penalty.

- Minimize current-sensing errors by connecting CSH\_ and CSL\_ directly across the current-sense resistor (RSENSE\_).
- When trade-offs in trace lengths must be made, it is preferable to allow the inductor charging path to be made longer than the discharge path. For example, it is better to allow some extra distance between the input capacitors and the high-side MOSFET than to allow distance between the inductor and the low-side MOSFET or between the inductor and the output filter capacitor.
- Route high-speed switching nodes (BST\_, LX\_, DH\_, and DL\_) away from sensitive analog areas (REF, FB\_, CSH\_, CSL\_).

#### **Layout Procedure**

- Place the power components first, with ground terminals adjacent (N<sub>L</sub> source, C<sub>IN</sub>, C<sub>OUT</sub>, and D<sub>L</sub> anode). If possible, make all these connections on the top layer with wide, copper-filled areas.
- 2) Mount the controller IC adjacent to the low-side MOSFET, preferably on the back side opposite NL\_ and NH\_ to keep LX\_, GND, DH\_, and the DL\_ gatedrive lines short and wide. The DL\_ and DH\_ gate traces must be short and wide (50 mils to 100 mils wide if the MOSFET is 1in from the controller IC) to keep the driver impedance low and for proper adaptive dead-time sensing.

- Group the gate-drive components (BST\_ diode and capacitor and LDO5 bypass capacitor) together near the controller IC.
- 4) Make the DC-DC controller ground connections as shown in Figures 1 and 10. This diagram can be viewed as having two separate ground planes: power ground, where all the high-power components go; and an analog ground plane for sensitive analog components. The analog ground plane and power ground plane must meet only at a single point directly at the IC.
- 5) Connect the output power planes directly to the output filter capacitor positive and negative terminals with multiple vias. Place the entire DC-DC converter circuit as close to the load as is practical.

\_Chip Information

TRANSISTOR COUNT: 5879 PROCESS: BICMOS



Figure 10. PCB Layout Example

### \_Ordering Information (continued)

PART	TEMP RANGE	PIN- PACKAGE	PKG CODE
MAX8717ETI+	-40°C to +85°C	28 Thin QFN 5mm x 5mm	T2855-6
MAX8756ETI+	-40°C to +85°C	28 Thin QFN 4mm x 4mm	T2855-6
MAX8757ETI+	-40°C to +85°C	28 Thin QFN 5mm x 5mm	T2855-6

+Denotes a lead-free package.

### Package Information

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)





### Package Information (continued)

(The package drawing(s) in this data sheet may not reflect the most current specifications. For the latest package outline information, go to <u>www.maxim-ic.com/packages</u>.)



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MAX8716/MAX8717/MAX8756/MAX8757



### MAX8716

#### **Part Number Table**



Part Number	Free Sample	Buy Direct	Package: TYPE PINS SIZE DRAWING CODE/VAR *	Тетр	RoHS/Lead-Free? Materials Analysis
MAX8716ETG		Buy	THIN QFN;24 pin;4X4X0.8mm Dwg: 21-0139E (PDF) Use pkgcode/variation: T2444-4*	-40°C to +85°C	RoHS/Lead-Free: No Materials Analysis
MAX8716ETG+	Sample	Buy	THIN QFN;24 pin;4X4X0.8mm Dwg: 21-0139E (PDF) Use pkgcode/variation: T2444+4*	-40°C to +85°C	RoHS/Lead-Free: Yes Materials Analysis
MAX8716ETG+T		Buy	THIN QFN;24 pin;4X4X0.8mm Dwg: 21-0139E (PDF) Use pkgcode/variation: T2444+4*	-40°C to +85°C	RoHS/Lead-Free: Yes Materials Analysis
MAX8716ETG-T		Buy		-40°C to +85°C	RoHS/Lead-Free: No

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### MAX8717

#### **Part Number Table**



Part Number	Free Sample	Buy Direct	Package: TYPE PINS SIZE DRAWING CODE/VAR *	Temp	RoHS/Lead-Free? Materials Analysis
MAX8717ETI		Buy	THIN QFN;28 pin;5x5x0.8mm Dwg: 21-0140K (PDF) Use pkgcode/variation: T2855-6*	-40°C to +85°C	RoHS/Lead-Free: No Materials Analysis
MAX8717ETI+	Sample	Buy	THIN QFN;28 pin;5x5x0.8mm Dwg: 21-0140K (PDF) Use pkgcode/variation: T2855+6*	-40°C to +85°C	RoHS/Lead-Free: Yes Materials Analysis
MAX8717ETI+T		Buy	THIN QFN;28 pin;5x5x0.8mm Dwg: 21-0140K (PDF) Use pkgcode/variation: T2855+6*	-40°C to +85°C	RoHS/Lead-Free: Yes Materials Analysis
MAX8717ETI-T		Buy		-40°C to +85°C	RoHS/Lead-Free: No

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![](_page_34_Picture_1.jpeg)

### MAX8757

### **Part Number Table**

1000001	
1. See the MAX8757	AX8757 QuickView Data Sheet for further information on this product family or download the full data sheet (PDF, 700kB).
2. Other opti	ons and links for purchasing parts are listed at: http://www.maxim-ic.com/sales.
3. Didn't Find one busine	d What You Need? Ask our applications engineers. Expert assistance in finding parts, usually within ess day.
<ol> <li>Part numb data sheet</li> </ol>	per suffixes: T or T&R = tape and reel; + = RoHS/lead-free; # = RoHS/lead-exempt. More: See full t or Part Naming Conventions.
5. * Some pa product us	ackages have variations, listed on the drawing. "PkgCode/Variation" tells which variation the ses.

Part Number	Free Sample	Buy Direct	Package:	TYPE PINS SIZE DRAWING CODE/VAR *	Тетр	RoHS/Lead-Free? Materials Analysis
MAX8757ETG+	Sample	Buy			-40°C to +85°C	RoHS/Lead-Free: Yes

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